

Green Products

SDUR12100

Technical Data Data Sheet N0388 Rev. -

SDUR12100 ULTRAFAST PLASTIC RECTIFIER

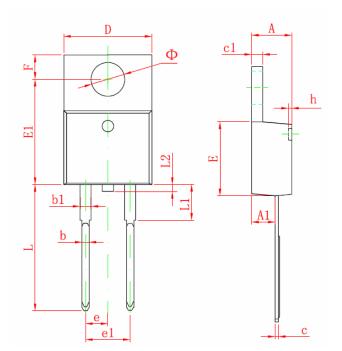
Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- **Snubber diode**
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- **Utra-Fast Switching** •
- **High Current Capability** .
- Low Reverse Leakage Current
- **High Surge Current Capability**
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions (In mm) and Marking:



Cymbol	Dimensions In Millimeters		
Symbol	Min	Мах	
A	4.470	4.670	
A1	2.520	2.820	
b	0.710	0.910	
b1	1.170	1.370	
с	0.310	0.530	
c1	1.170	1.370	
D	10.010	10.310	
E	8.500	8.900	
E1	12.060	12.460	
e	2.540 TYP		
e1	4.980	5.180	
F	2.590	2.890	
h	0.000	0.300	
L	13.400	13.800	
L1	3.560	3.960	
L2		1.000	
Φ	3.735	3.935	

TO-220AC

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- 1.Cathode
- 2.Anode

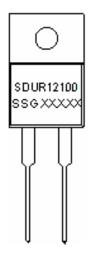


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Marking Diagram:



Where XXXXX is YYWWL

SDUR	= Device Type
12	= Forward Current (12A)
100	= Reverse Voltage (1000V)
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SDUR12100	TO-220AC	Elmon / tubo
	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	1000	V
Max. Average Forward	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	12	А
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	T _J =45°C 8.3ms, Half Sine pulse	80	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V _{F1}	@ 12A, Pulse, T _J = 25°C	2.7	V
	V _{F2}	@ 12A, Pulse, T _J = 150°C	2.1	V
Max. Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25°C	150	μA
	I _{R2}	$@V_R = rated V_R$ T _J = 125°C	4000	μA
Max. Reverse Recovery Time	t _{rr}	I_F =1A, -di/dt=50A/us,V _R =30V,and T _J = 25°C	50	ns

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-40 to +150	°C
Max. Storage Temperature	T _{stg}	-	-40 to +150	°C
Maximum Thermal Resistance Junction to Case	R _{thJC}	DC operation	1.6	K/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			



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